

Characterization of Low-Energy Electron-Irradiated Reduced Graphene Oxide using Raman Spectroscopy and Desorption Analysis

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Motivation and Background

Prior Studies on Hydrogenation/Irradiation of Graphene Drums and CVD Graphene

Materials and Procedure

Single-Walled Carbon Nanotubes and Reduced Graphene Oxide

Results and Analysis

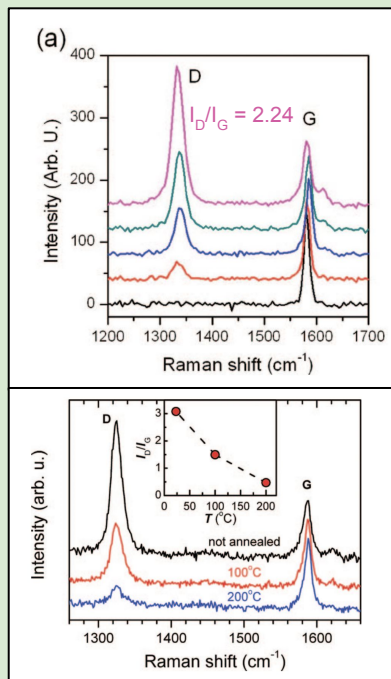
Raman of Reduced Graphene Oxide and SWCNT, Temperature-Programmed Desorption of SWCNT

Conclusions and Future Work

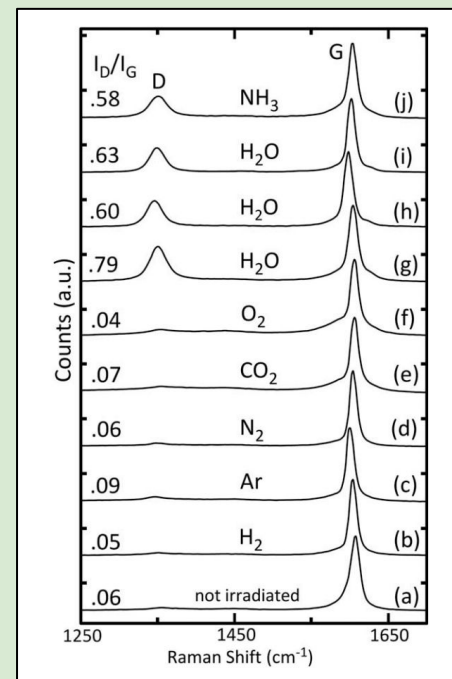
Summary, Future Work, and Thank you!

Previous reports on in-vacuum electron irradiation of CVD-grown graphene shows evidence that defects produced may be **hydrogen adsorbates**.

Ryu, S., Han, M. Y., Maultzsch, J., Heinz, T. F., Kim, P., Steigerwald, M. L., & Brus, L. E. (2008), "Reversible Basal Plane Hydrogenation of Graphene", Nano Letters, 8(12), 4597–4602.



Jones, J. D., Mahajan, K. K., Williams, W. H., Ecton, P. A., Mo, Y., & Perez, J. M. (2010), "Formation of graphane and partially hydrogenated graphene by electron irradiation of adsorbates on graphene", Carbon, 48(8), 2335–2340.



Electron Irradiation of Graphene Drums

4/15

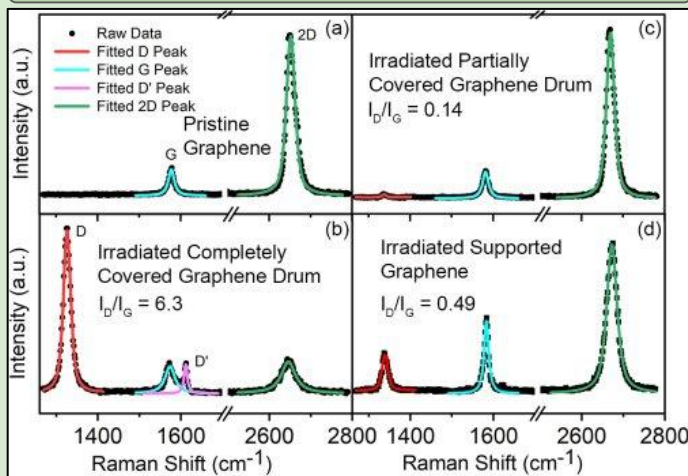
Irradiated
using SEM

15 keV

1×10^{17}
 e^-/cm^2

$\uparrow I_D/I_G$ for
covered
drums

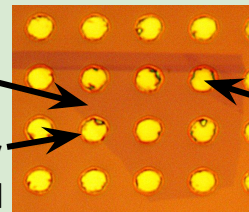
Raman of Different Locations



Optical Image of
Graphene Drum

Supported
Graphene

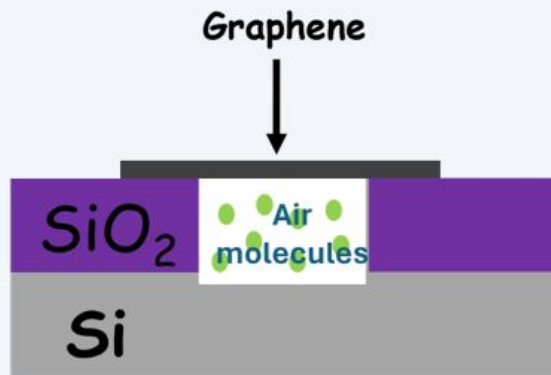
Partially
Covered



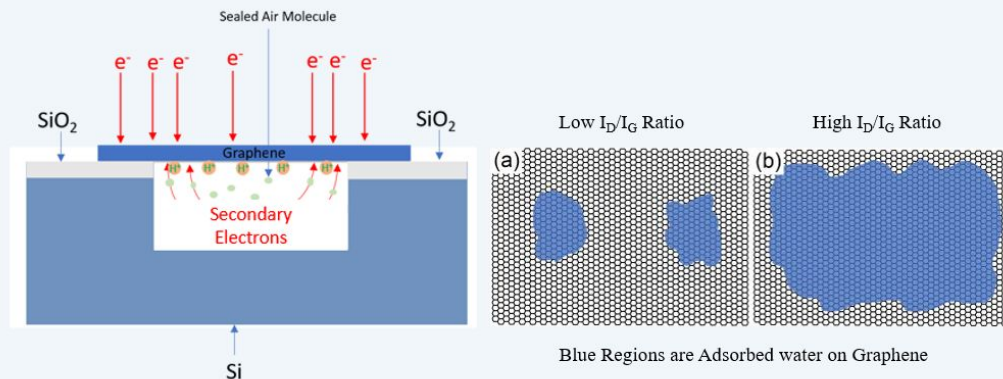
Fully
Covered

If hydrogen adsorbates are also produced when irradiating graphene at near-atmospheric pressure, then the observed high defect densities may imply high hydrogen coverages that **meet or exceed the Department of Energy's 4.5 weight % for hydrogen storage**

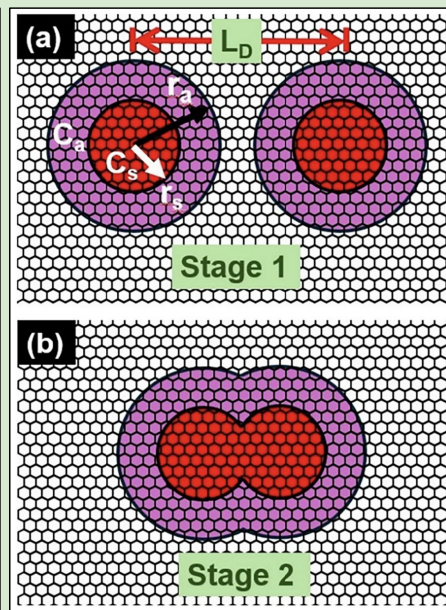
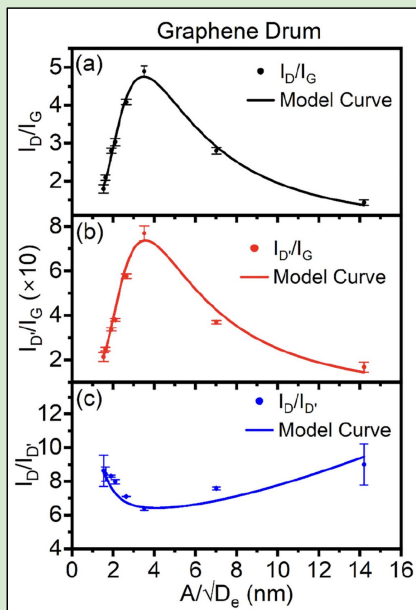
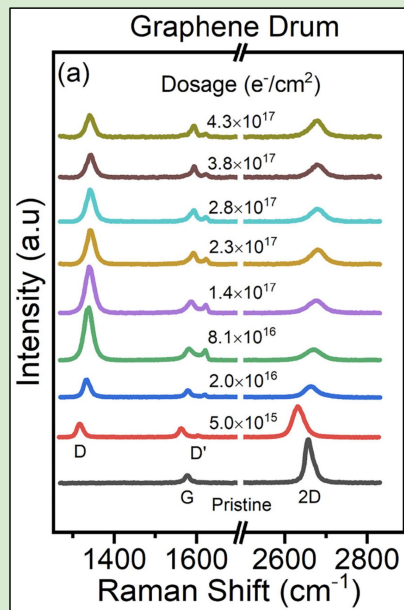
Mechanism for Irradiation of Graphene Drums



- Hole Diameter: 4.6 μm
- Hole Depth: 500 nm
- Density of Air at S.T.P: 2.7×10^{19} molecules/cm³
- Leakage rate of air in graphene drum: 2×10^3 Atoms/s
- 0.96 atm of air in graphene drum after placement in a vacuum chamber for 1 hour



$$\frac{I_D}{I_G} = C_a \frac{r_a^2 - r_s^2}{r_a^2 - 2r_s^2} \left[e^{\frac{-\pi r_s^2}{L_D^2}} - e^{\frac{-\pi(r_a^2 - r_s^2)}{L_D^2}} \right] + C_s \left[1 - e^{\frac{-\pi r_s^2}{L_D^2}} \right]$$

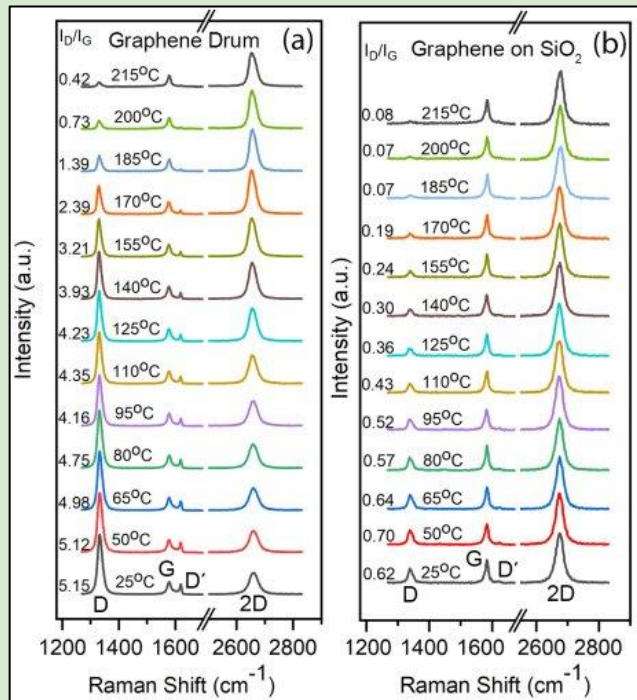


Changes in
Raman Spectra
of graphene
drums can be
modeled using
the Local
Activation
Model¹

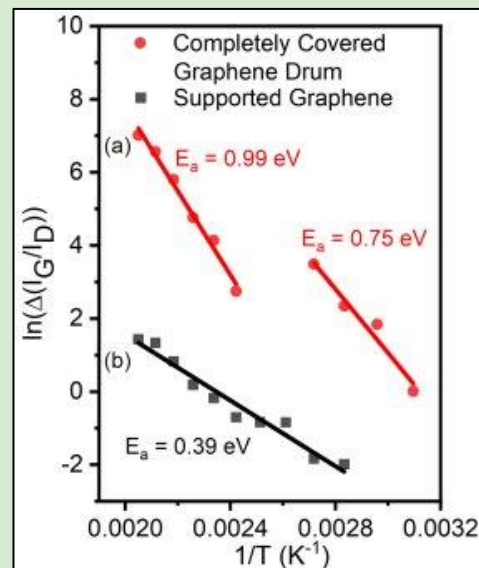
¹Lucchese, Márcia Maria, F. Stavale, EH Martins Ferreira, Cecília Vilani, MV de O. Moutinho, Rodrigo B. Capaz, Carlos Alberto Achete, and A. Jorio. "Quantifying ion-induced defects and Raman relaxation length in graphene." Carbon 48, no. 5 (2010): 1592-1597.

I_D/I_G decreases
with annealing
temperature

Activation
energies in-line
with H and OH
related
desorption
processes



Arrhenius Plot



**Migration
Barriers*:**

Hydrogen:
0.3eV – 1.0eV

Hydroxyl group:
0.5eV – 1.0eV

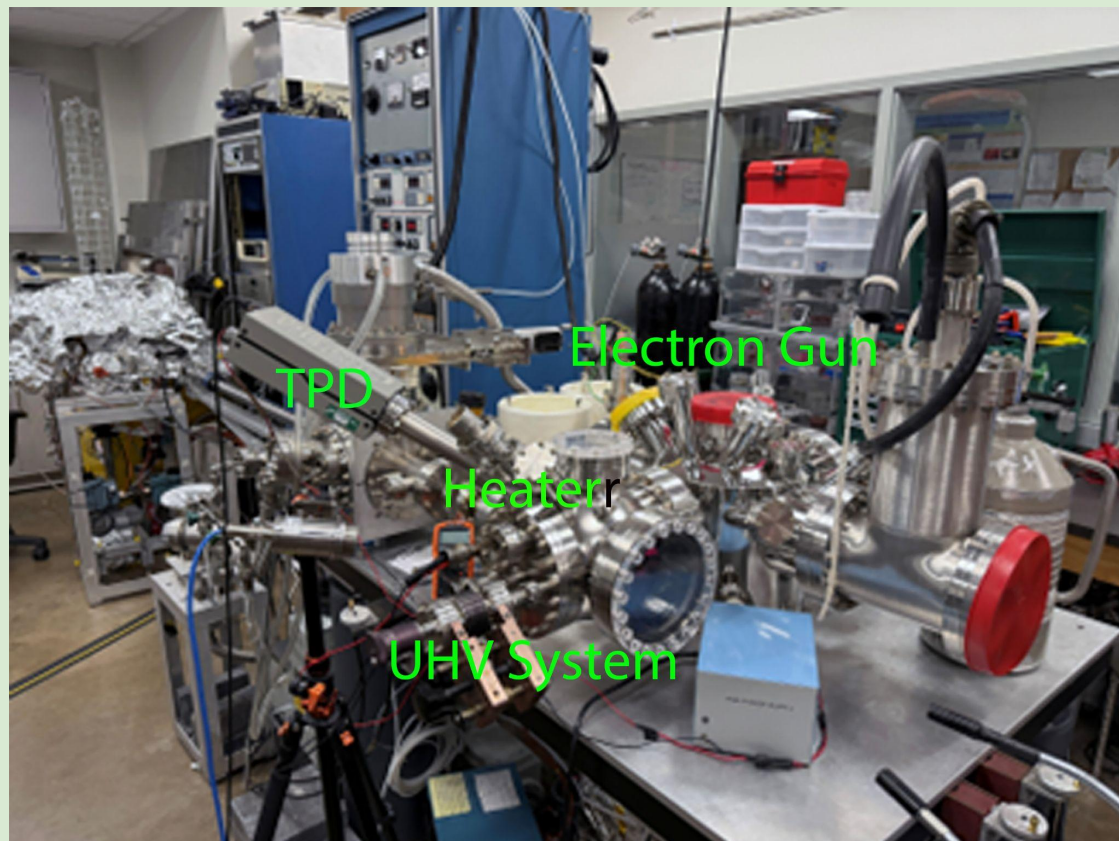
Hydroxyl group
with
attached H_2O :
**0.6eV
– 0.7eV**

*Boukhvalov, D. W.
(2010). Physical
Chemistry Chemical
Physics, 12(47),
15367-15371.

Ultra-High-Vacuum Irradiation System

CVD Irradiated in UHV to
avoid carbonaceous
contamination from SEM
breakup of hydrocarbons

For use in XPS and TPD
analysis

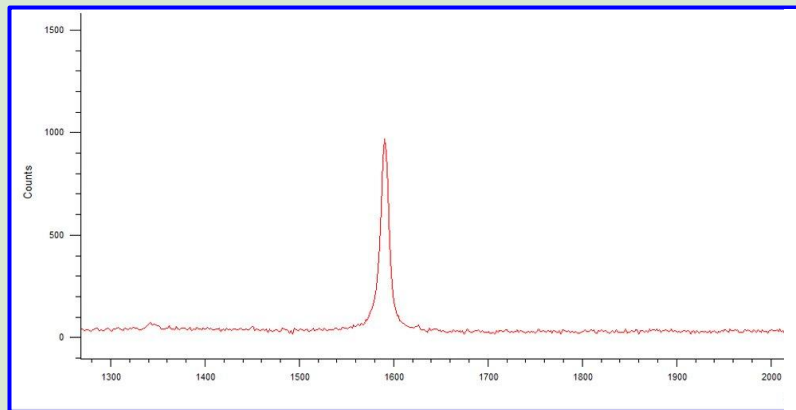


Irradiated in UHV to avoid carbonaceous contamination from SEM breakup of hydrocarbons

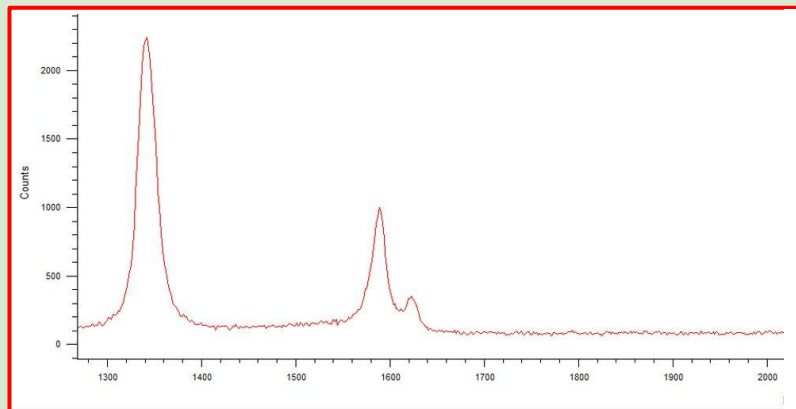
Irradiated $I_D/I_G = 2.5$ indicates high defect density

Irradiated $I_D/I_D' = 11.4$, from 8 - 13 indicates sp^3 type defects

Purchased from Graphenea, Inc



Before
UHV
Electron
Irradiation

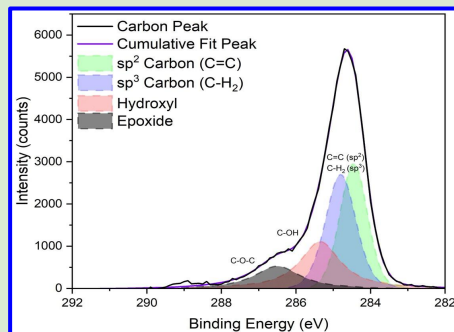


After UHV
Electron
Irradiation

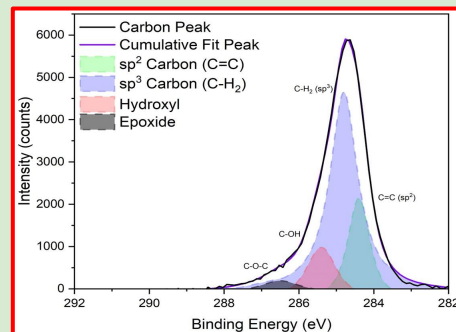
XPS of CVD Graphene

Large-Area CVD
Graphene
irradiated at 1.5
keV and 1×10^{17}
 e^-/cm^2 ,
annealed at
270 °C for 10
min,
re-irradiated
with same
parameters

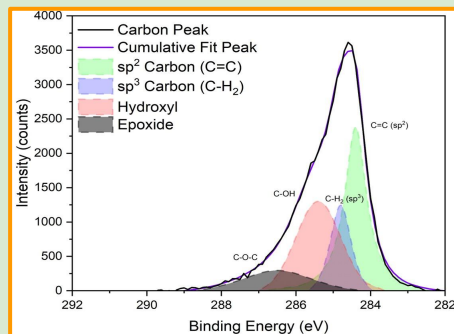
Purchased from
Graphenea, Inc



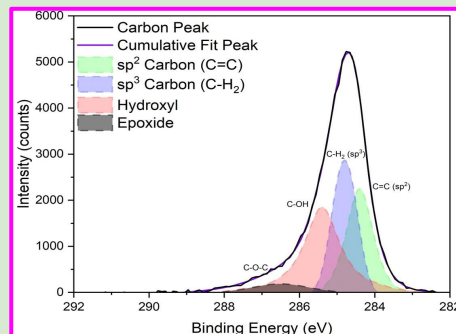
XPS C1s Spectrum **Before UHV**
Irradiation



XPS C1s Spectrum **After UHV**
Irradiation



XPS C1s Spectrum **After Annealing**



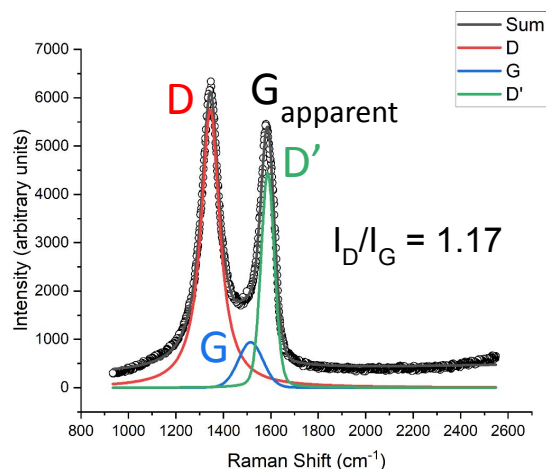
XPS C1s Spectrum **After**
Re-Irradiation

C1s spectrum for
pristine graphene ($\uparrow$ sp²
carbon) has asymmetric
tail towards higher
binding energy

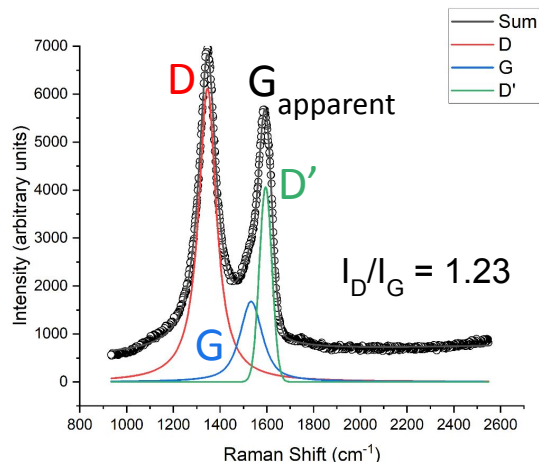
C1s spectrum for
sample with $\uparrow$ sp³
carbon is symmetric
and shifted to higher
binding energy

Annealing as low as 250
°C is expected to
remove hydrogen from
graphene

Before UHV Electron Irradiation



After Electron Irradiation



Deconvolution into D peak, and
G + D' Peaks that form G^{apparent}¹

No change in D-peak

Possibly due to edge defects in
powder

I_D/I_G increased, but heavily
dependent on fitting

Also performed XPS showing no
increase in sp³, but a decrease in
OH. Presented by Park et al.
tomorrow

¹King, A. A. K., Davies, B. R., Noorbehesht, N., Newman, P., Church, T. L., Harris, A. T., Razal, J. M., & Minett, A. I. (2016). A New Raman Metric for the Characterisation of Graphene oxide and its Derivatives. Scientific Reports, 6(1).
<https://doi.org/10.1038/srep19491>

Carbon nanotubes
maintain carbon lattice
without oxygen defects

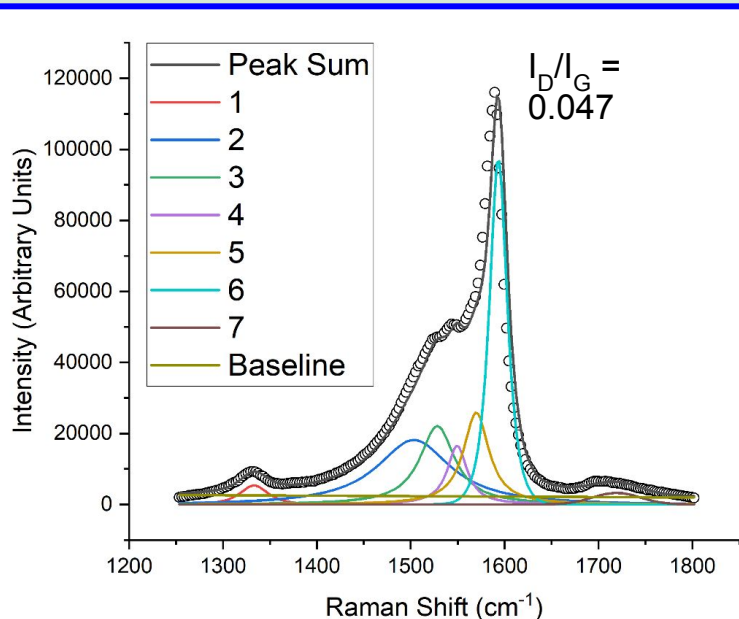
Studied Purified
HiPCo-grown SWCNTs
and unpurified tubes
that contain Fe catalysts
+ amorphous carbon

Dispersed in DMF,
deposited onto SiO₂

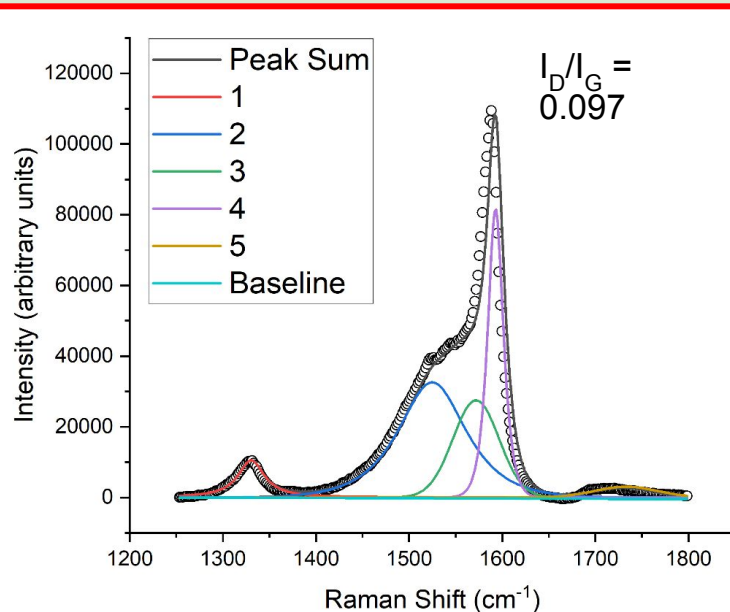
Irradiated in UHV at 10^{-10}
Torr, 2 nA, 2.55×10^{15}
 e^-/cm^2 at 1.5 keV

Results: Raman of Unpurified HiPCO SWCNT

Pre-Irradiation Raman Spectra of Unpurified HiPCO-Grown SWCNT Pre-TPD



Post-Irradiation Raman Spectra of Unpurified HiPCO-Grown SWCNT Pre-TPD



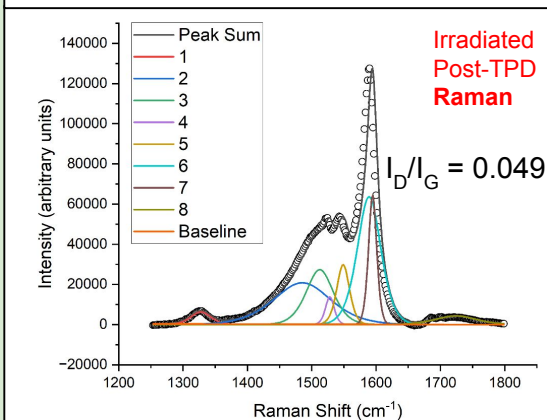
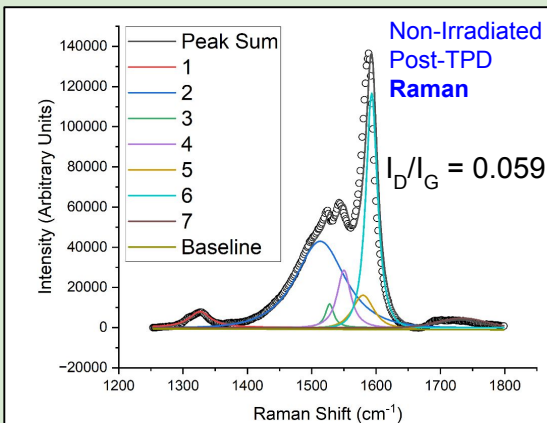
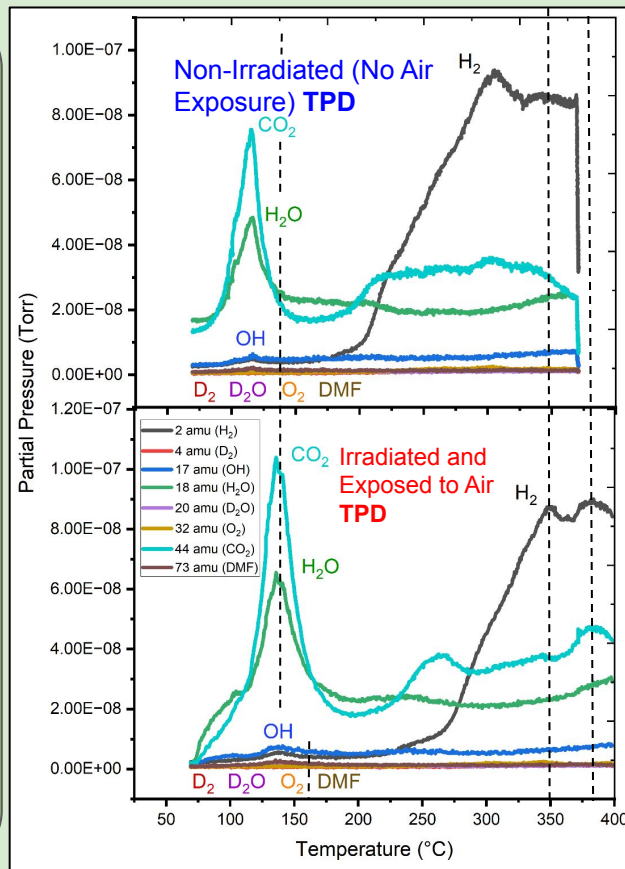
Irradiation induces increase in D-peak

Changes in substructure of G-Peak

More noticeable increase in I_D/I_G , but still dependent on fitting complex peaks

Unpurified HiPCO
SWNT

Low-temperature
 H_2 peak
disappears,
higher
temperature
peak appears -
indicates
irradiation
possibly
produced
hydrogen species
with higher
binding energy



Raman overall
shows $\uparrow I_D/I_G$
after irradiation,
 $\downarrow$ after thermal
desorption

- We found that powdered forms of graphene such as Reduced Graphene Oxide do not show the same Raman clear properties of exfoliated and CVD graphene when irradiated with electrons. We believe that this is due to residual oxidation or edge defects.
- We therefore investigated carbon nanotubes that can be produced in large quantities, but do not have edge defects.
- In carbon nanotubes, we observed the similar effects of irradiation in Raman spectra as observed in exfoliated and CVD graphene.
- Detailed TPD studies of electron-irradiated Reduced Graphene Oxide and SWCNT are currently being carried out.
- There is a talk tomorrow by my colleague Jian Park et al. about the TPD of Reduced Graphene Oxide.

**Thank
you!
Questions
Welcome!**



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References

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